## Massachusetts Institute of Technology Department of Electrical Engineering and Computer Science

6.002 – Circuits & Electronics Spring 2007 Homework #3 Handout S07-019

## Issued 2/22/07 - Due 3/2/07

Reading: Chapter 5, Chapter 6.1-6.10.

**Exercise 3.1**. The number of Boolean functions of one variable (*A*) is four ( $F_1$ ,  $F_2$ ,  $F_3$ , and  $F_4$ ), as it can be learned from the truth table given in Table 1. Then:

a. How many different Boolean functions are there of 2 variables, and of 3 variables?

**b.** How many different Boolean functions are there of *n* variables?

Α	$F_1$	$F_2$	$F_3$	$F_4$
0	0	0	1	1
1	0	1	0	1

Table 1: Truth table for the different Boolean Functions of one variable.

Exercise 3.2. Do Exercise 5.6, page 275 of the textbook, parts *a*, *b*, and *d*.

Exercise 3.3. Do Exercise 6.2, page 322 of the textbook.

Problem 3.1. Do Problem 5.2, page 278 of the textbook.



Figure 1: Input/Output transfer characteristic for inverter of Problem 3.2.

**Problem 3.2**. An inverter has the input/output transfer characteristic shown in Fig. 1. This inverter obeys the static discipline for suitable choices of the voltages  $V_{OL}$ ,  $V_{IL}$ ,  $V_{IH}$ , and  $V_{OH}$ , (see Fig. 5.8 on page 250 of the textbook), and those are such that  $NM_H = NM_L$ . Then:

**a.** Give values of  $V_{OL}$ ,  $V_{IL}$ ,  $V_{IH}$ , and  $V_{OH}$  that actually achieve the static discipline with the maximum positive noise margin.

**b.** What is the noise margin you obtained?

**Problem 3.3** For this problem, consider the convention that a logical one corresponds to a high voltage level and a logical zero corresponds to a low voltage level. Thus, when the voltage  $v_A$  associated with the Boolean variable A is high (3V), A = 1. When  $v_A$  is low ( $\approx 0V$ ), A = 0. The same relation holds with  $v_B$  and B,  $v_C$  and C. Assume also the following:

- The high voltage level is much greater than the threshold voltage.
- The "on" resistance of the MOSFET is  $100\Omega$ .
- The "off" resistance of the MOSFET is  $100M\Omega$ .

Then, for *each* circuit in Fig. 2:

**a.** Generate a truth table which shows how the variable *C* (associated with  $v_C$ ) depends on the inputs A (associated with  $v_A$ ) and *B* (associated with  $v_B$ ).

**b.** For each particular entry of *C* in the corresponding truth table of part **a**., find the value of the output voltage  $v_c$ .



Figure 2: Circuits for Problem 3.3.